



University of Virginia
Condensed Matter Seminar
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Counting statistics of electron transport in nanostructures

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Theory collaborators:

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Alessandro Braggio (Genova)
Tobias Brandes (Berlin)
Karel Netočný (Prague)
Antti-Pekka Jauho (Copenhagen/Helsinki)

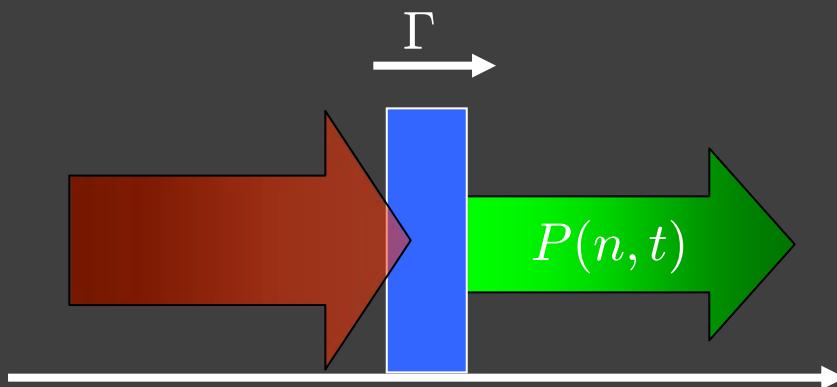
Experiments:

Christian Fricke (Hannover)
Frank Hohls (Hannover)
Rolf J. Haug (Hannover)

Recent papers:

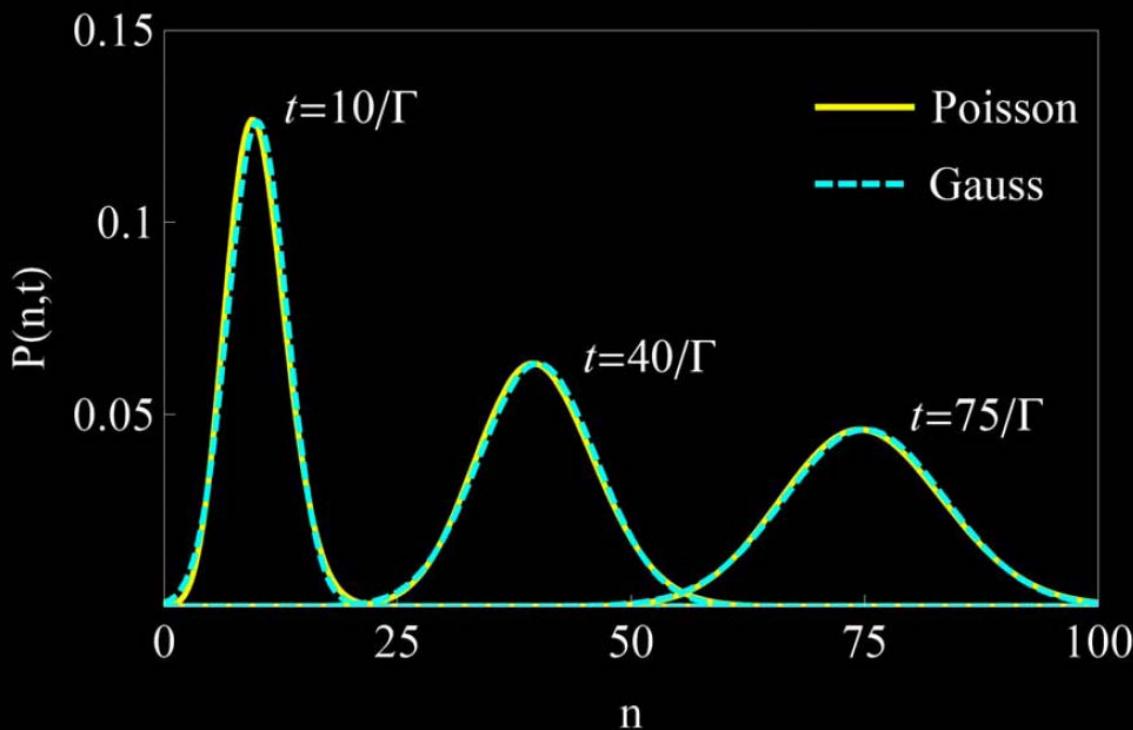
C. Flindt *et al.*, PRL **100**, 150601 (2008)
C. Flindt *et al.*, PNAS **106**, 10116 (2009)
C. Flindt *et al.*, in prep. (2009)

Introduction to counting statistics



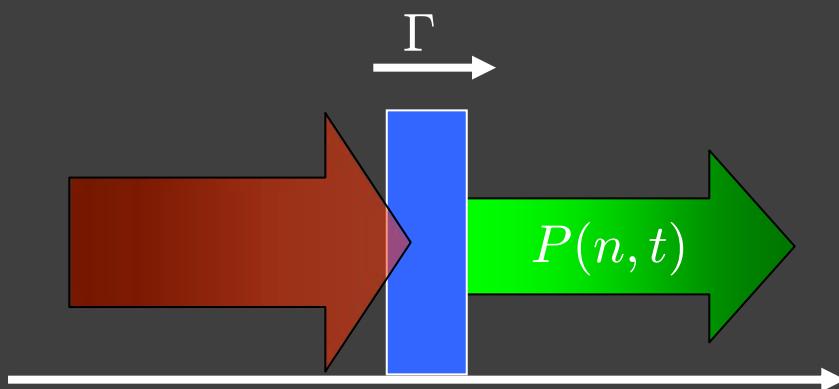
Uncorrelated, classical particles transmitted through a barrier with rate $\Gamma \Rightarrow$ Poisson process

$$P(n, t) = \frac{(\Gamma t)^n}{n!} e^{-\Gamma t}$$



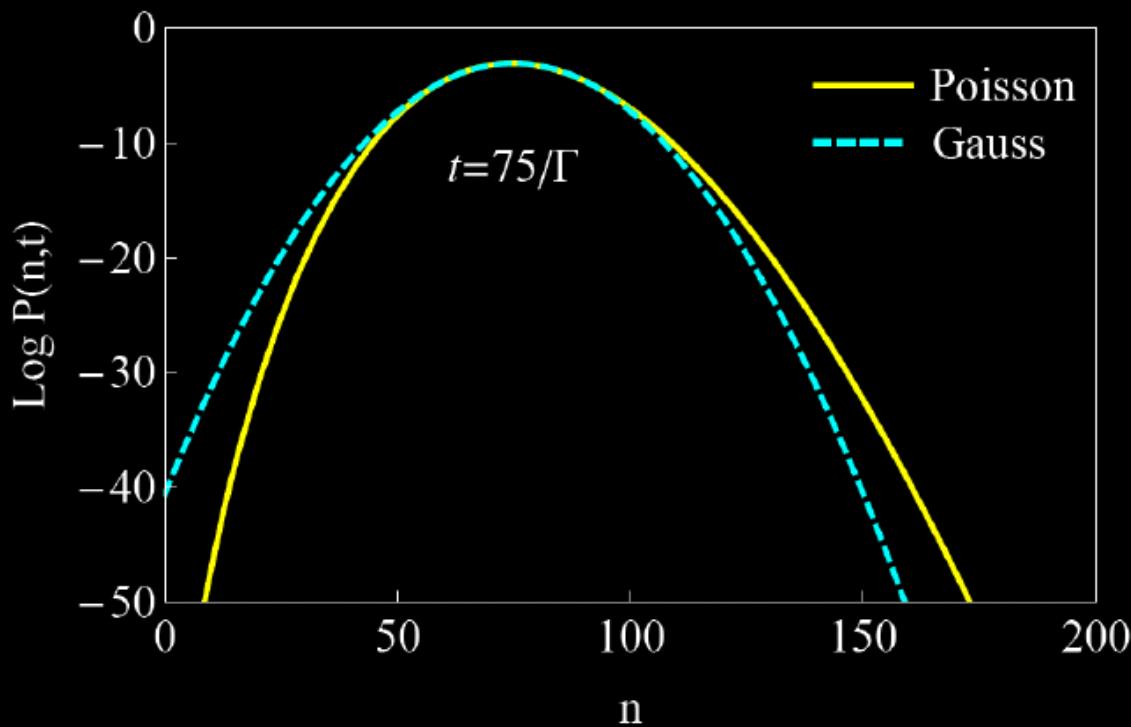
Looks Gaussian...
... but look closer!!

Introduction to counting statistics



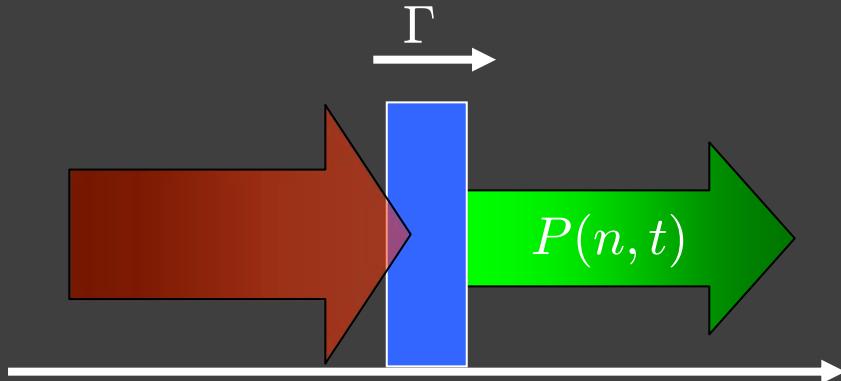
Uncorrelated, classical particles transmitted through a barrier with rate $\Gamma \Rightarrow$ Poisson process

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- Peak well-described
- Tails not captured by Gaussian approximation
⇒ Consider cumulants

Introduction to counting statistics



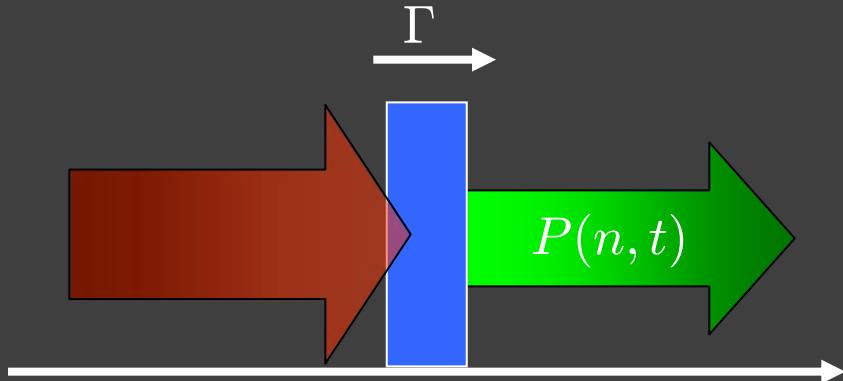
Uncorrelated, classical particles transmitted through a barrier with rate $\Gamma \Rightarrow$ Poisson process

$$P(n, t) = \frac{(\Gamma t)^n}{n!} e^{-\Gamma t}$$

Cumulants:

- 1st cumulant – mean: $\langle\langle n \rangle\rangle = \langle n \rangle$
- 2nd cumulant – variance: $\langle\langle n^2 \rangle\rangle = \langle (n - \langle n \rangle)^2 \rangle$
- 3rd cumulant – skewness: $\langle\langle n^3 \rangle\rangle = \langle (n - \langle n \rangle)^3 \rangle$
- General definition: $\langle\langle n^m \rangle\rangle = \frac{\partial^m \mathcal{S}(\chi, t)}{\partial(i\chi)^m} |_{\chi \rightarrow 0}$ (χ : “counting field”)
- Cumulant generating function (CGF): $e^{\mathcal{S}(\chi, t)} \equiv \sum_n P(n, t) e^{in\chi}$
- Poisson process: $\langle\langle n^m \rangle\rangle = \Gamma t$. Gauss distribution: $\langle\langle n^m \rangle\rangle = 0, m > 2$

Introduction to counting statistics



Uncorrelated, classical particles transmitted through a barrier with rate $\Gamma \Rightarrow$ Poisson process

$$P(n, t) = \frac{(\Gamma t)^n}{n!} e^{-\Gamma t}$$

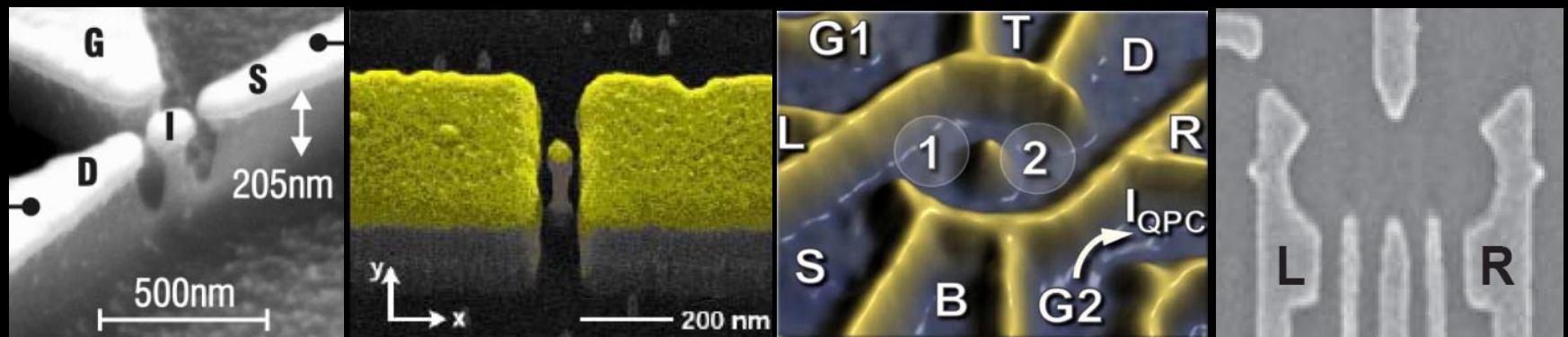
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Non-zero higher order cumulants reveal non-Gaussian behavior!

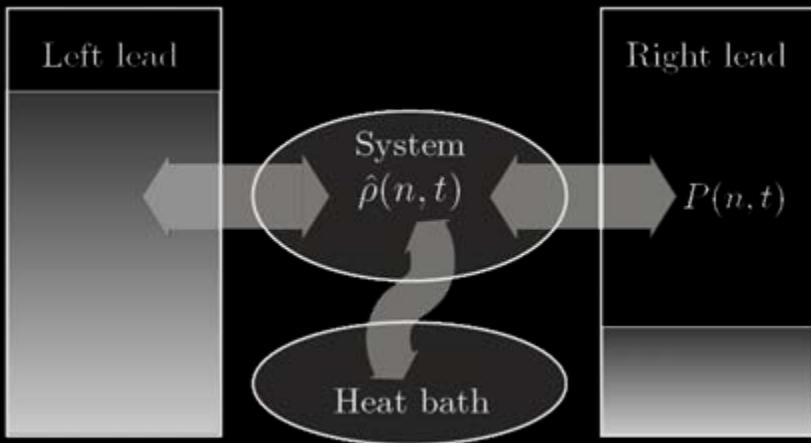
This talk – Outline

- Introduction to counting statistics
- General theory (open-quantum-systems approach)
Example: a nano-electromechanical system (NEMS)
- Memory effects (due to environment)
Example: dissipative double quantum dot (open spin-boson model)
- High-order cumulants
Example: single quantum dot (experiment)
- Summary and outlook



Pictures from München, Wisconsin, ETH-Zürich, and Harvard

General theory (open-quantum-systems approach)



n -resolved reduced density matrix:

- R. J. Cook, PRA **23**, 1243 (1981)
- Yu. Makhlin *et al.*, RMP **73**, 357 (2001)

$$\begin{aligned}\hat{\rho}(n,t) &\Rightarrow P(n,t) = \text{Tr}\{\hat{\rho}(n,t)\} \\ &\Rightarrow e^{\mathcal{S}(\chi,t)} = \text{Tr}\{\hat{\rho}(\chi,t)\}\end{aligned}$$

Assuming Markovian dynamics (e.g. weak coupling):

$$\frac{d}{dt}\hat{\rho}(\chi,t) = \mathcal{W}(\chi)\hat{\rho}(\chi,t)$$

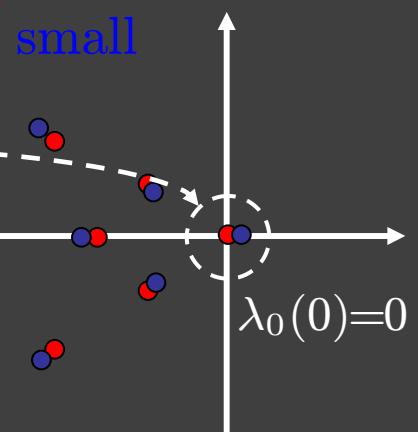
$$\Rightarrow \hat{\rho}(\chi,t) = e^{\mathcal{W}(\chi)t}\hat{\rho}(\chi,0)$$

$$\Rightarrow e^{\mathcal{S}(\chi,t)} = \text{Tr}\{e^{\mathcal{W}(\chi)t}\hat{\rho}(\chi,0)\} \rightarrow e^{\lambda_0(\chi)t} \text{ for large } t$$

$$\Rightarrow \langle\langle n^m \rangle\rangle = t \frac{\partial^m \lambda_0(\chi)}{\partial(i\chi)^m} \Big|_{\chi \rightarrow 0} \Rightarrow \langle\langle I^m \rangle\rangle = \frac{\partial^m \lambda_0(\chi)}{\partial(i\chi)^m} \Big|_{\chi \rightarrow 0}$$

Eigenvalues of $\mathcal{W}(\chi)$

$\chi = 0$
 χ small



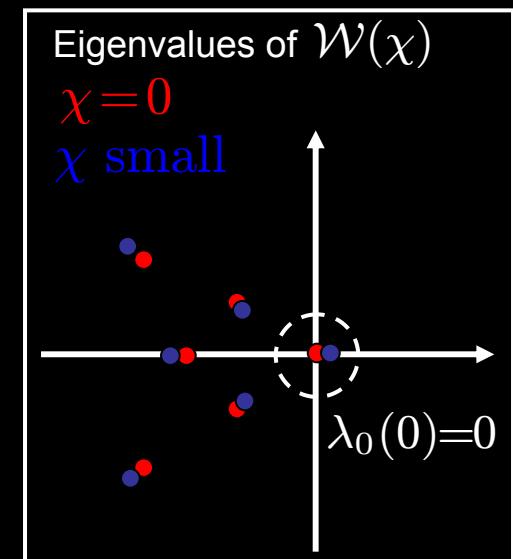
General theory (open-quantum-systems approach)

Technical issue: How do I solve the eigenproblem?

$$\mathcal{W}(\chi)|0(\chi)\rangle\rangle = \lambda_0(\chi)|0(\chi)\rangle\rangle$$

Solution: Perturbation theory in χ !

- Cumulants: $\lambda_0(\chi) = \sum_n \frac{(i\chi)^n}{n!} \langle\langle I^n \rangle\rangle = 0$
- Unperturbed problem: $\mathcal{W}(0)|0(0)\rangle\rangle = \overbrace{\lambda_0(0)}^0 |0(0)\rangle\rangle$
- Perturbation: $\mathcal{W}'(\chi) \equiv \mathcal{W}(\chi) - \mathcal{W}(0) = \sum_n \frac{(i\chi)^n}{n!} \mathcal{W}^{(n)}$



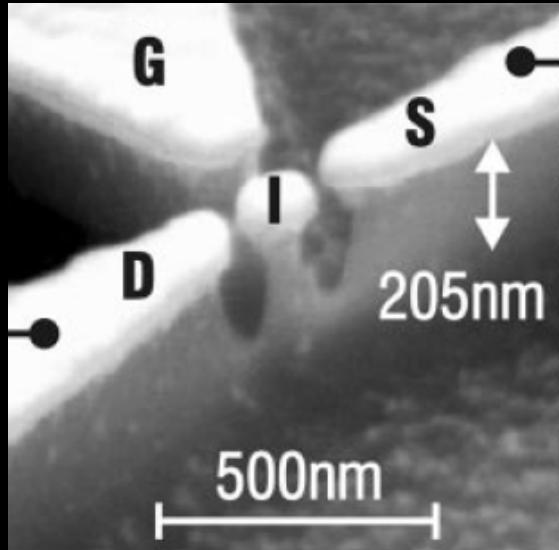
Perturbation theory can be done recursively using the building blocks:

$$\mathcal{P} = \mathcal{P}^2 \equiv |0(0)\rangle\rangle\langle\langle\tilde{0}(0)|, \quad \mathcal{Q} = \mathcal{Q}^2 \equiv 1 - \mathcal{P}, \quad \mathcal{R} \equiv \mathcal{Q} \frac{1}{\mathcal{W}(0)} \mathcal{Q}$$

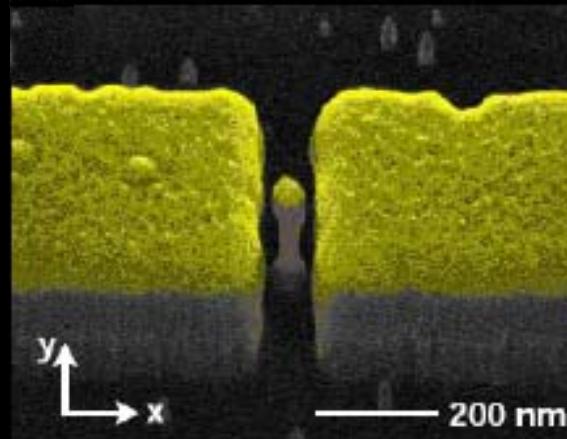
Recursive scheme: $\langle\langle I^n \rangle\rangle = \sum_{m=1}^n \binom{n}{m} \langle\langle \tilde{0} | \mathcal{W}^{(m)} | 0^{(n-m)} \rangle\rangle$
 (numerically stable up to
 ~100'th cumulant)

$$|0^{(n)}\rangle\rangle = \mathcal{R} \sum_{m=1}^n \binom{n}{m} [\langle\langle I^m \rangle\rangle - \mathcal{W}^{(m)}] |0^{(n-m)}\rangle\rangle$$

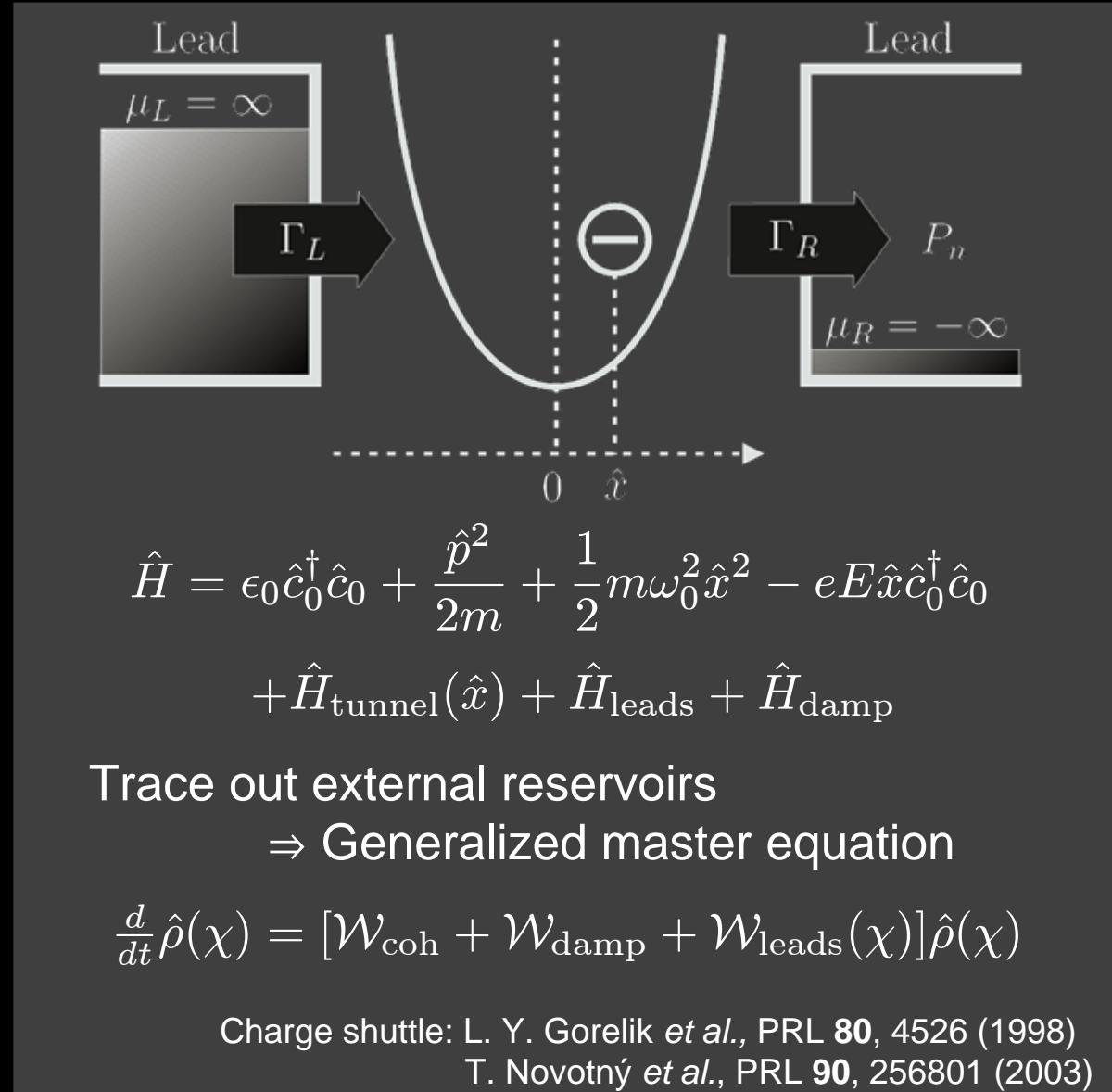
Example: A nano-electromechanical system (NEMS)



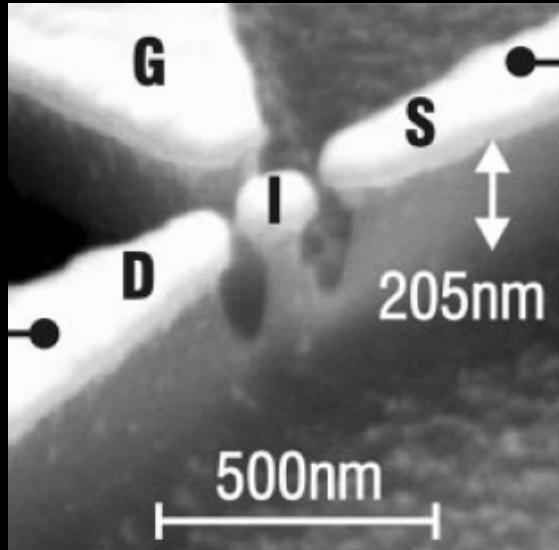
D. V. Scheible *et al.*,
APL **84**, 4632 (2004)



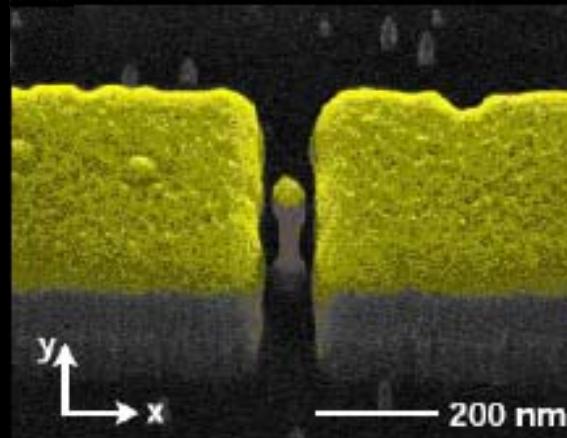
H. S. Kim *et al.*,
Nanotech. **18**, 065201 (2007)



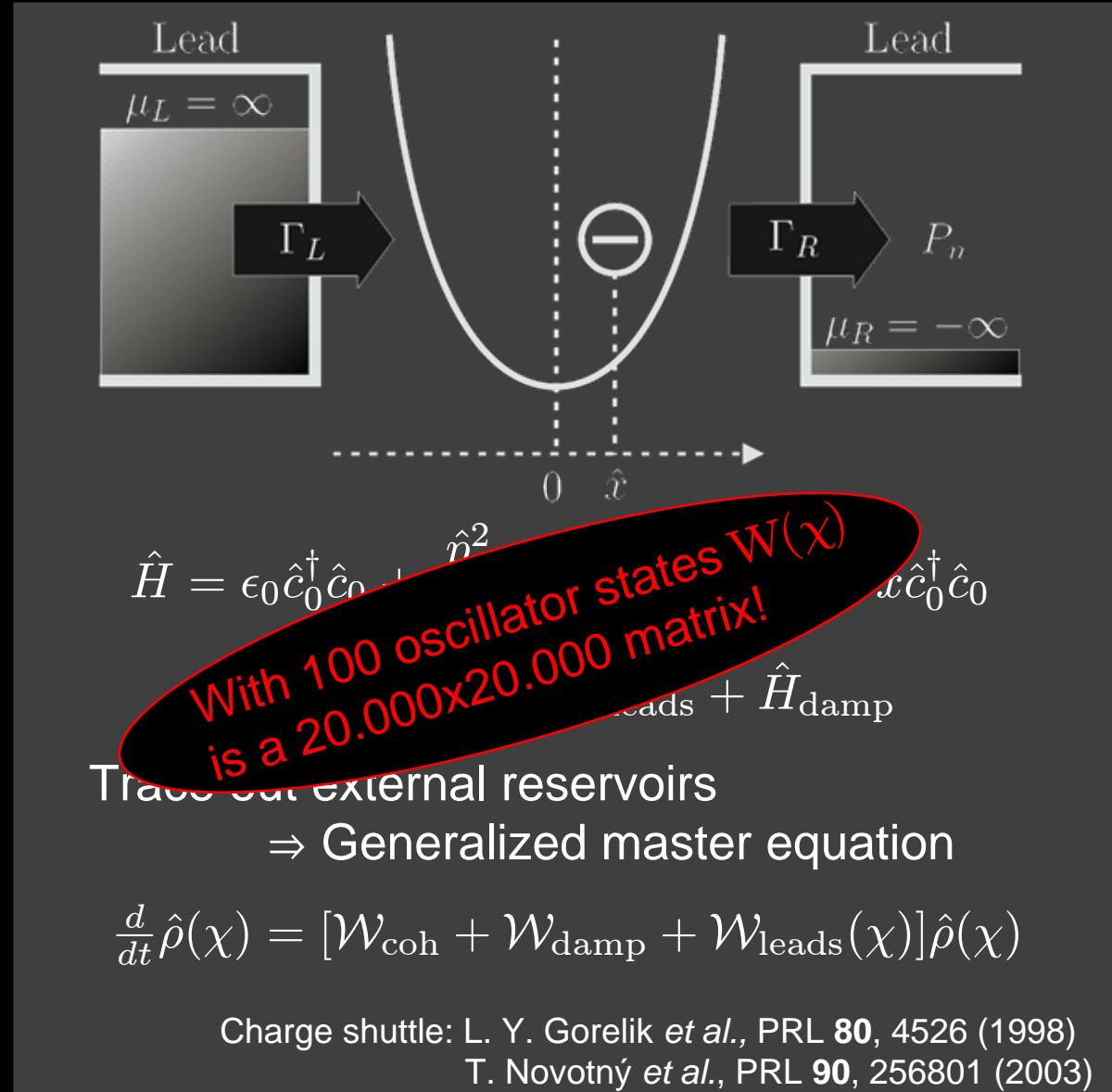
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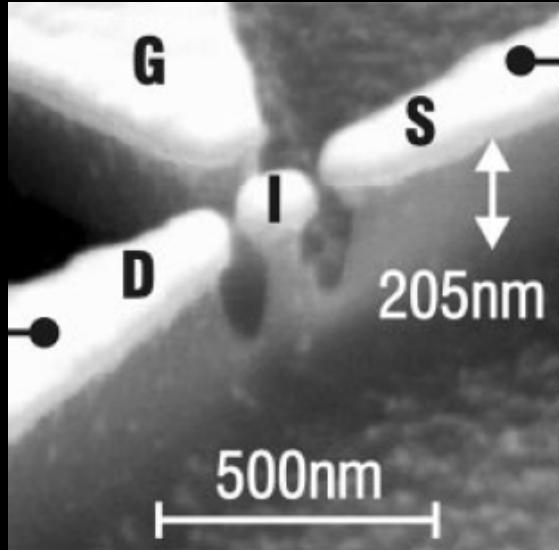
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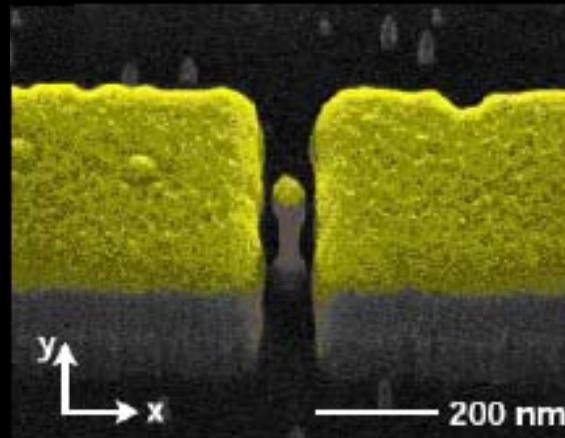
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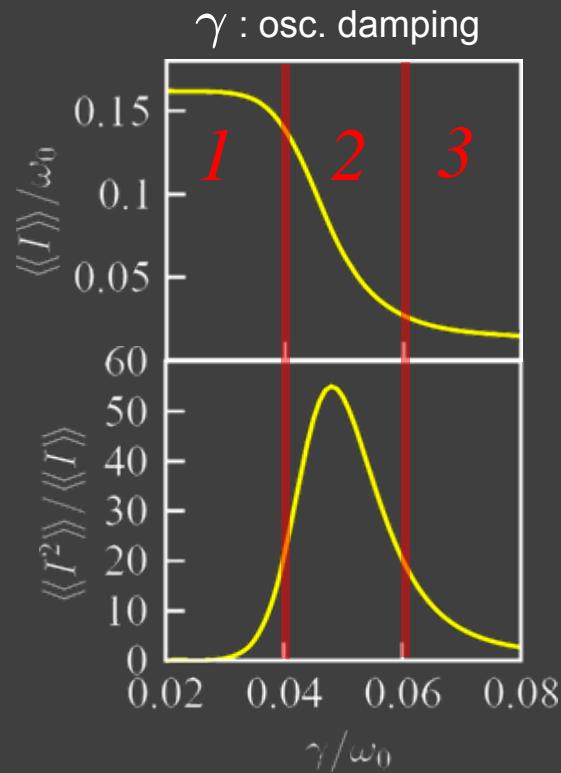


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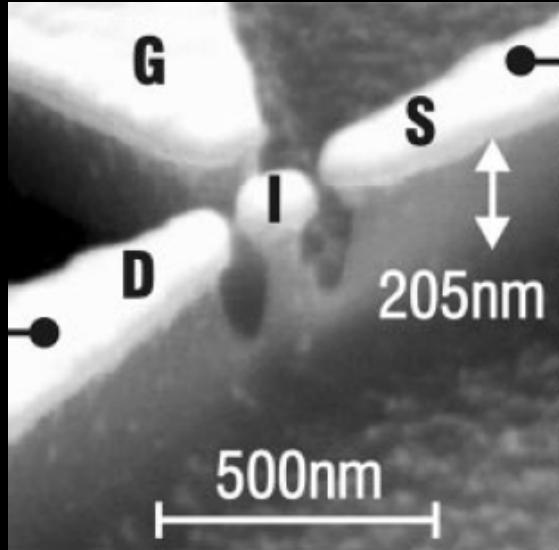


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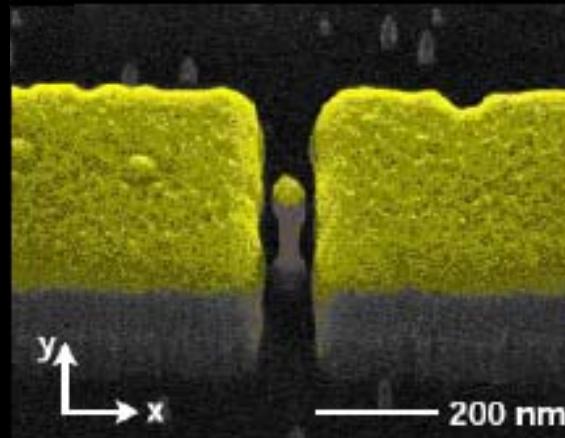
Mean current $\langle\langle I^1 \rangle\rangle$ & zero-frequency noise $\langle\langle I^2 \rangle\rangle$



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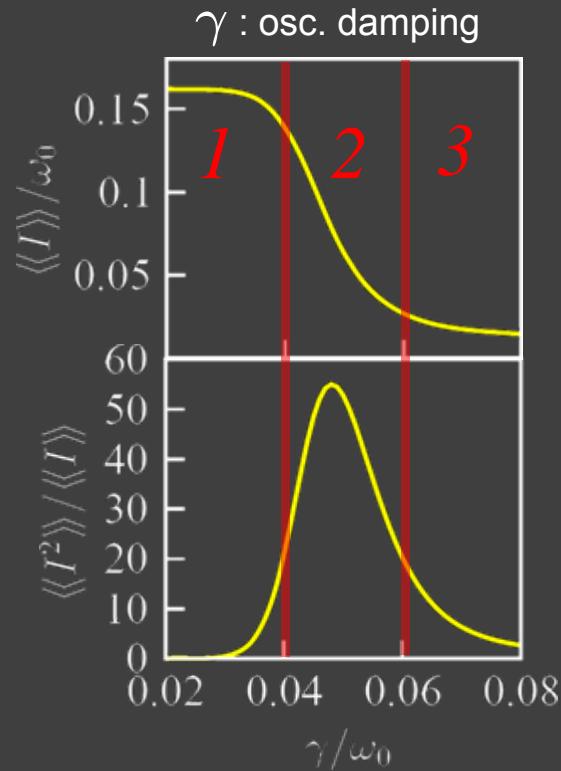


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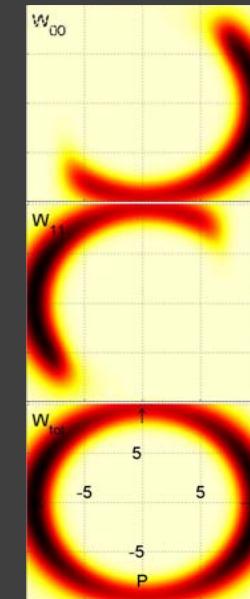
Mean current $\langle\langle I^1 \rangle\rangle$ & zero-frequency noise $\langle\langle I^2 \rangle\rangle$

1. *Shuttle regime:*

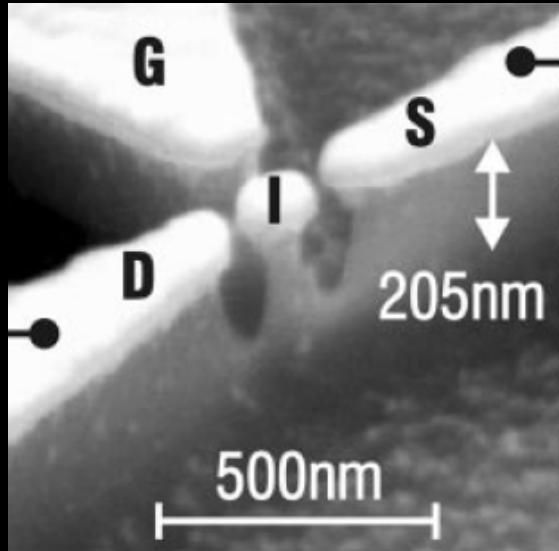
$$\langle\langle I^1 \rangle\rangle \simeq \frac{\omega_0}{2\pi}, \langle\langle I^2 \rangle\rangle \simeq 0$$



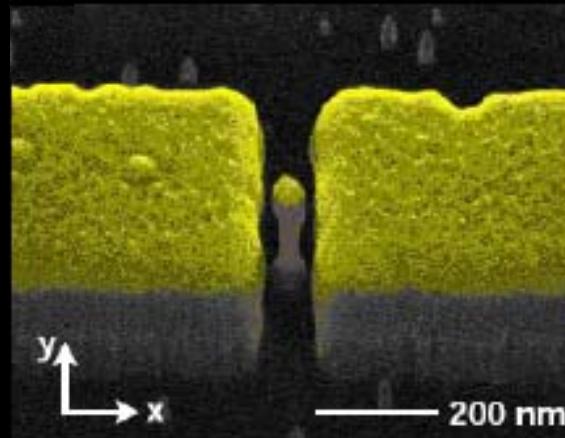
Osc. phase space



Example: A nano-electromechanical system (NEMS)



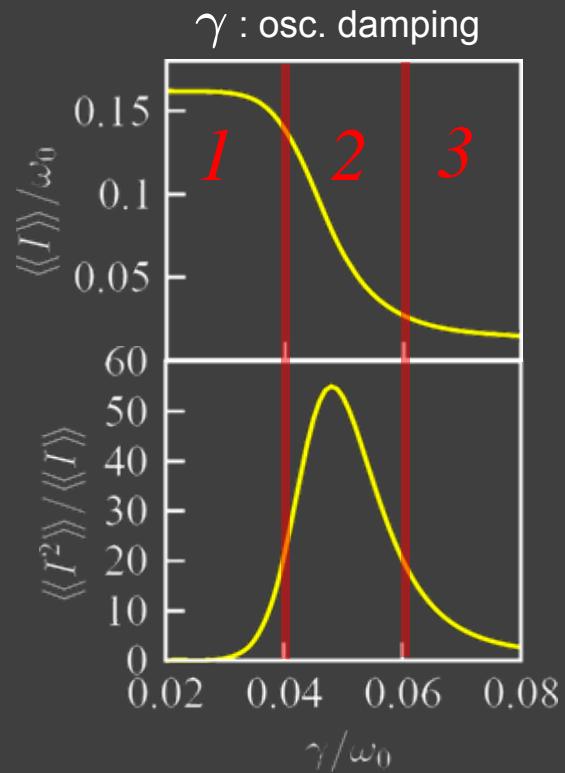
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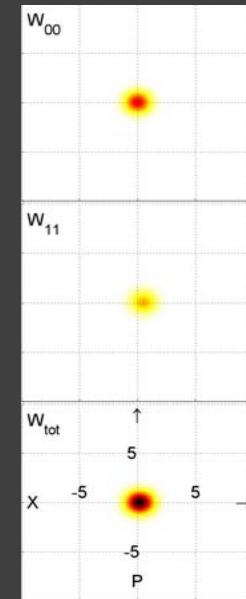
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Mean current $\langle\langle I^1 \rangle\rangle$ & zero-frequency noise $\langle\langle I^2 \rangle\rangle$

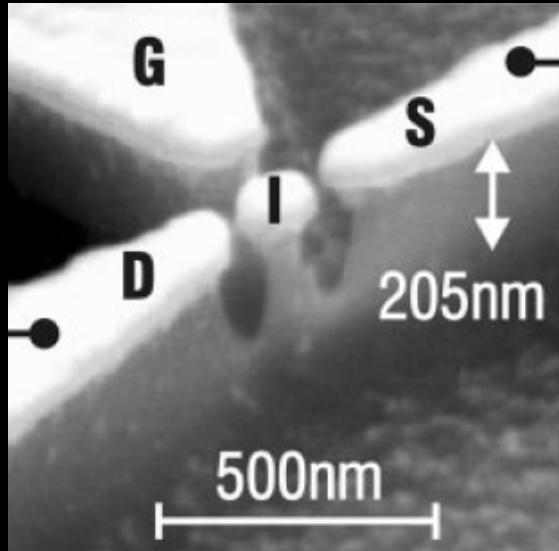
3. “Static dot” regime



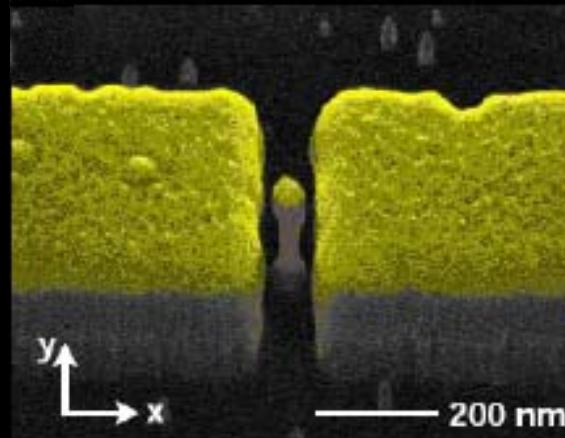
Osc. phase space



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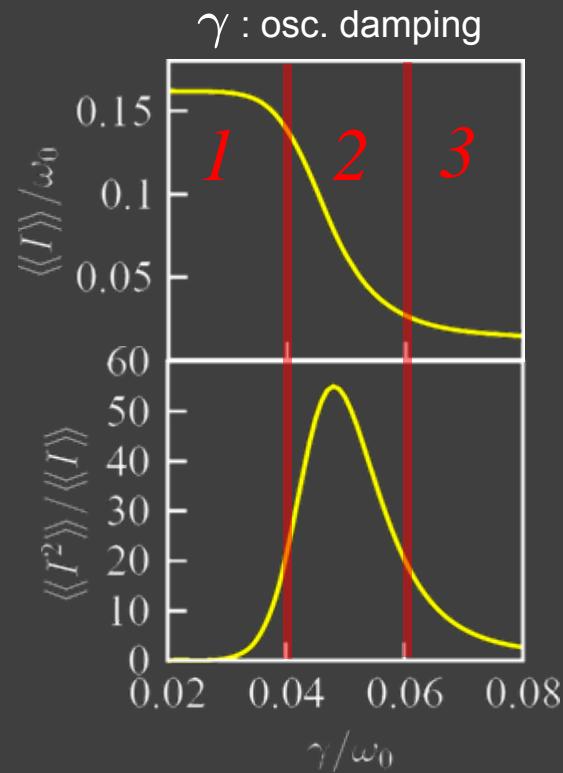
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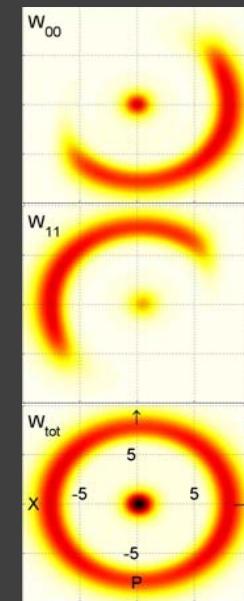
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Mean current $\langle\langle I^1 \rangle\rangle$ & zero-frequency noise $\langle\langle I^2 \rangle\rangle$

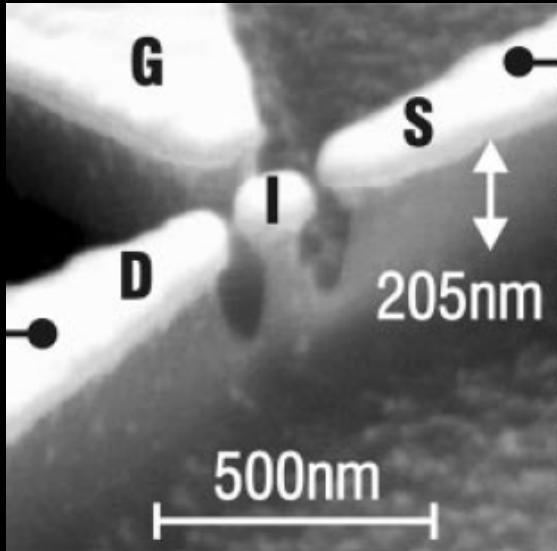
2. “Co-existence” regime – enhanced noise



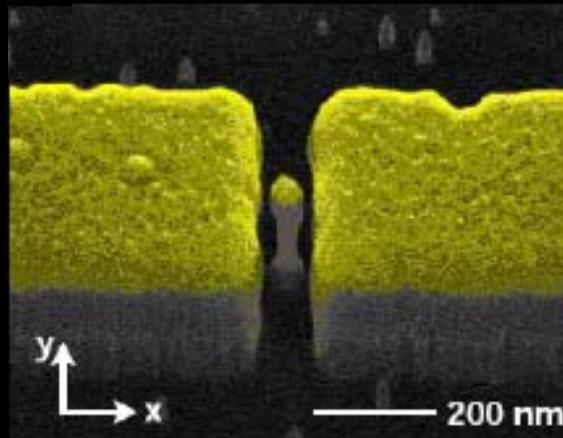
Osc. phase space



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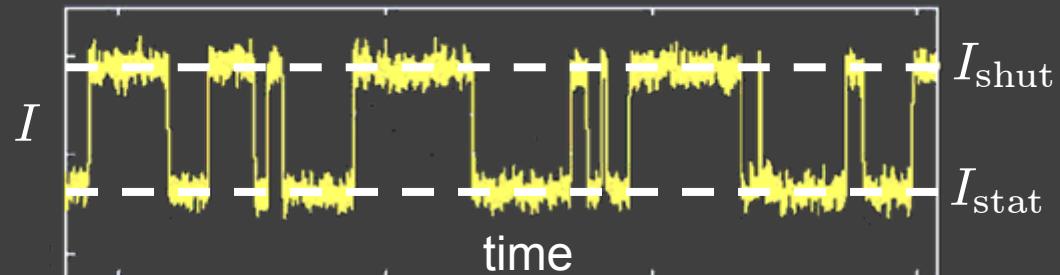


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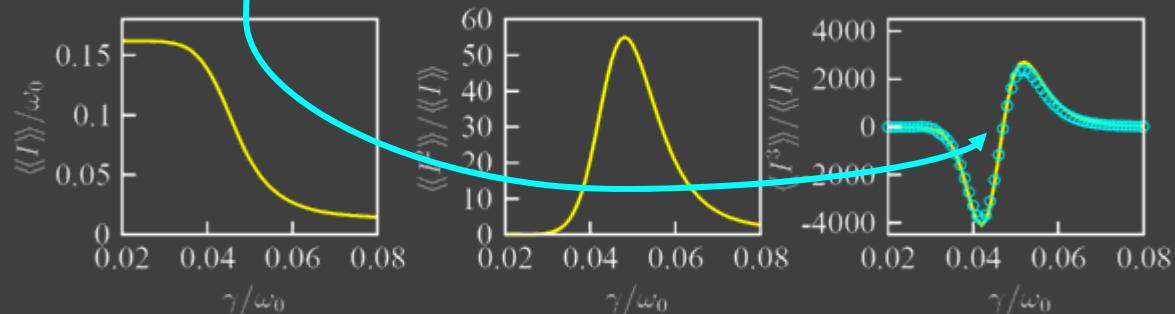
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Nanotech. **18**, 065201 (2007)

Noise enhancement due to mechanical bistability causing random telegraph noise (RTN)?



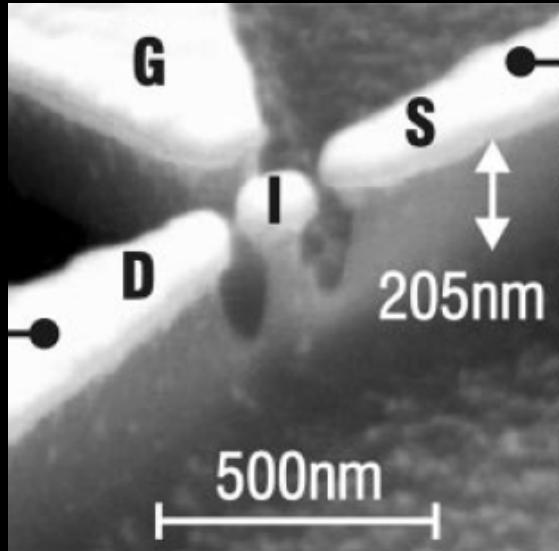
For RTN:

$$\langle\langle I^3 \rangle\rangle = 3 \langle\langle I^2 \rangle\rangle \frac{(I_{\text{shut}} + I_{\text{stat}})/2 - \langle\langle I^1 \rangle\rangle}{(I_{\text{shut}} - \langle\langle I^1 \rangle\rangle)(\langle\langle I^1 \rangle\rangle - I_{\text{stat}})}$$

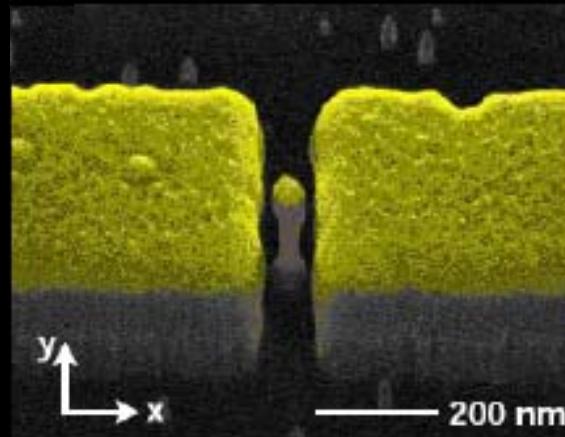


C. Flindt *et al.*, EPL **69**, 475 (2005)

Example: A nano-electromechanical system (NEMS)

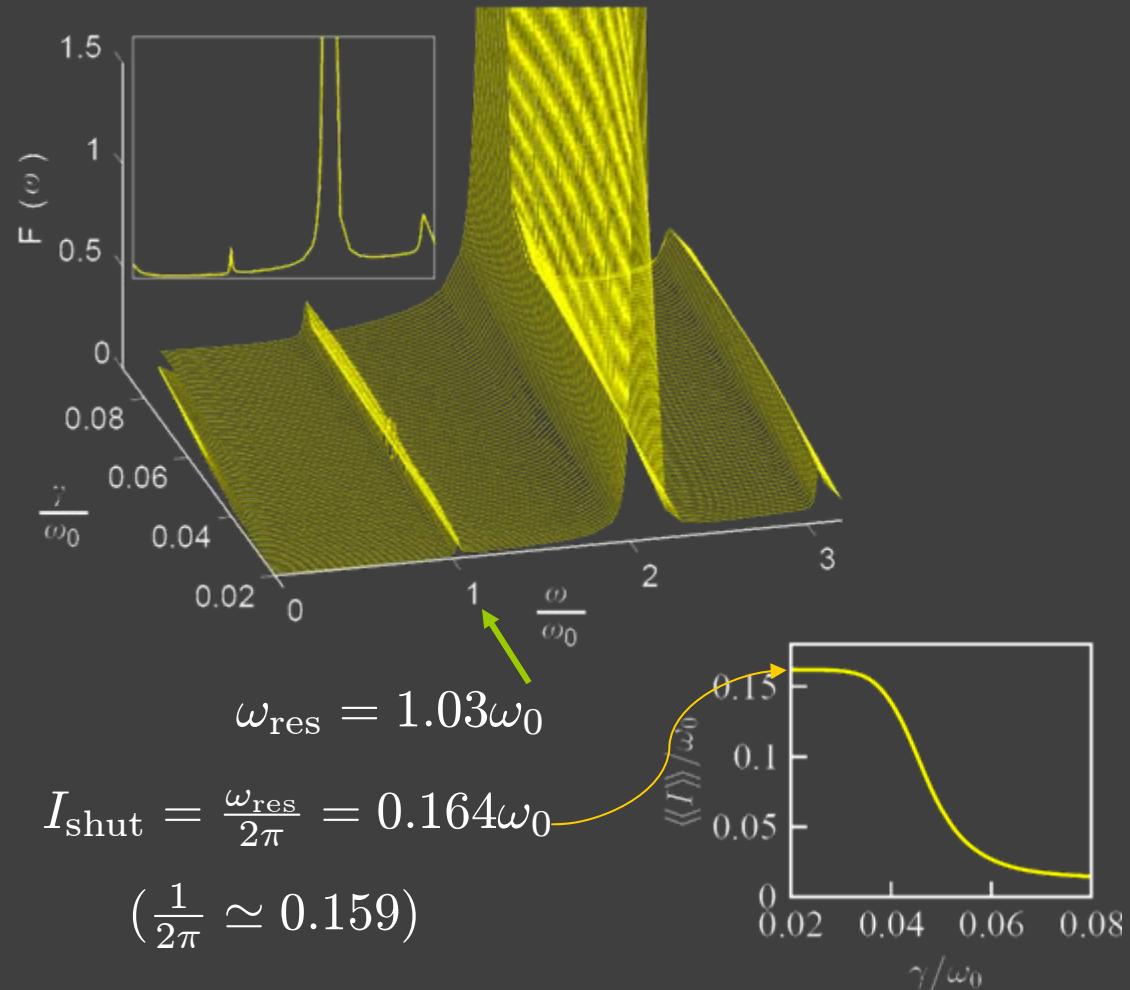


D. V. Scheible *et al.*,
APL **84**, 4632 (2004)



H. S. Kim *et al.*,
Nanotech. **18**, 065201 (2007)

Finite-frequency noise $F(\omega)$:



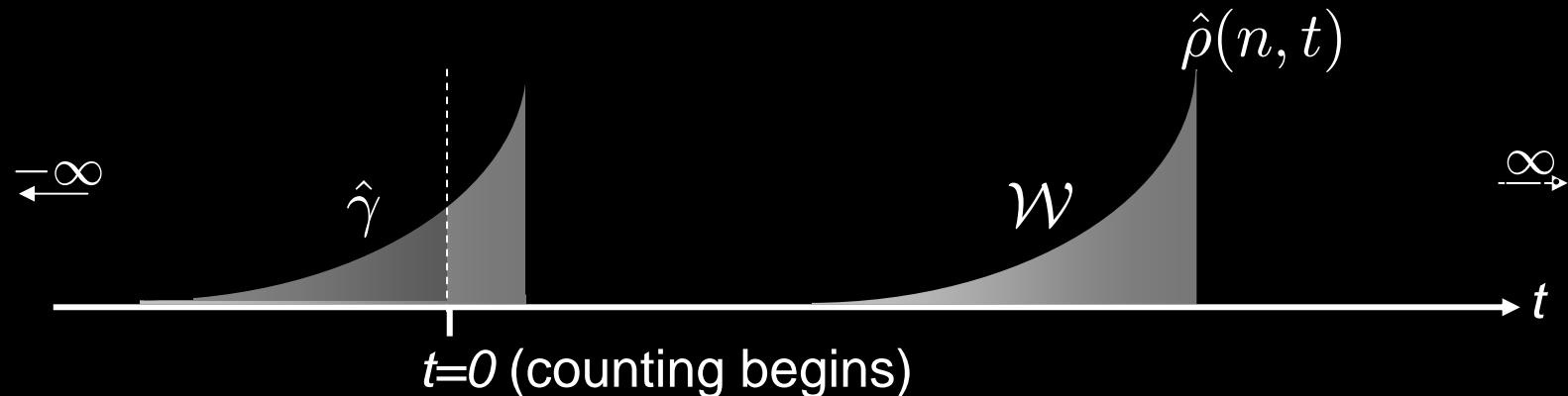
C. Flindt *et al.*, Physica E **29**, 411 (2005)

Memory effects (due to environment)

Non-Markovian generalized master equation (à la Nakajima-Zwanzig)

$$\frac{d}{dt} \hat{\rho}(n, t) = \sum_{n'} \int_0^t dt' \mathcal{W}(n - n', t - t') \hat{\rho}(n', t') + \hat{\gamma}(n, t)$$

electron counting memory kernel initial correlations
(important at finite freq.)



In Laplace space: $\hat{\rho}(\chi, z) = \mathcal{G}(\chi, z) [\hat{\rho}(\chi, t = 0) + \hat{\gamma}(\chi, z)]$
and χ -space

$$\mathcal{G}(\chi, z) \equiv [z - \mathcal{W}(\chi, z)]^{-1}$$

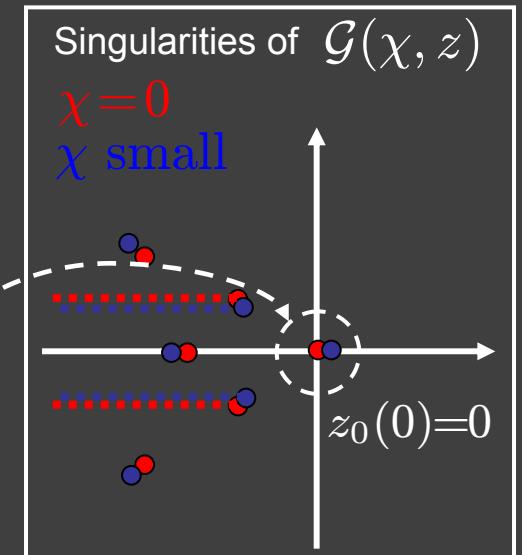
Memory effects (due to environment)

$$\hat{\rho}(\chi, z) = \mathcal{G}(\chi, z) [\hat{\rho}(\chi, t=0) + \hat{\gamma}(\chi, z)]$$

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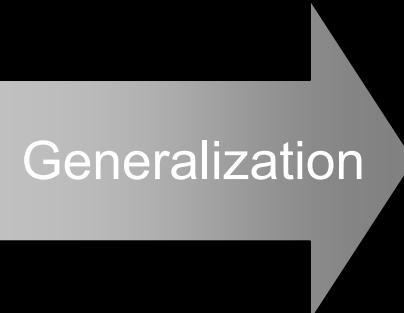
Long- t limit given by pole z_0 of $\mathcal{G}(\chi, z)$ close to 0:

$$\mathcal{S}(\chi, t) \rightarrow z_0(\chi)t$$



Markovian case:

$$z_0 - \lambda_0(\chi) = 0$$



Non-Markovian case:

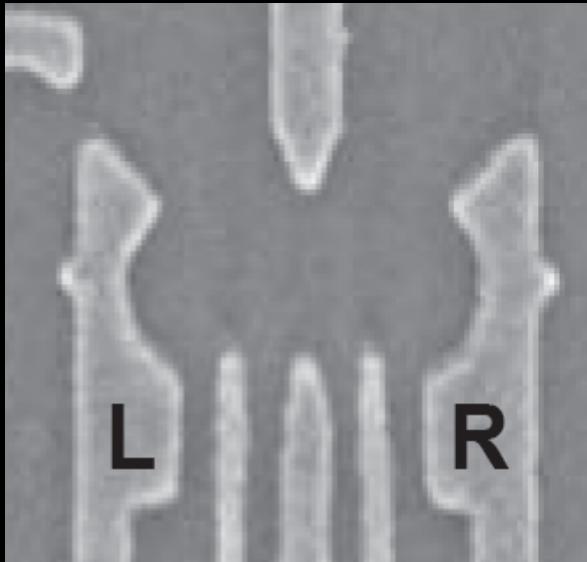
$$z_0 - \lambda_0(\chi, z_0) = 0$$

Can also be solved recursively using perturbation theory in χ and z .

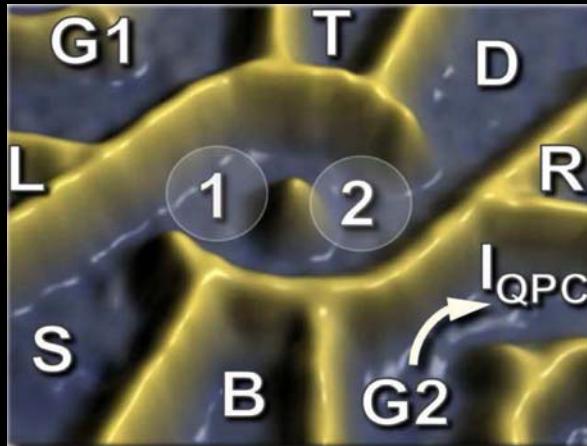
A. Braggio *et al.*, PRL **96**, 026805 (2006)

C. Flindt *et al.*, PRL **100**, 150601 (2008) + in prep. (2009)

Example: dissipative double quantum dot



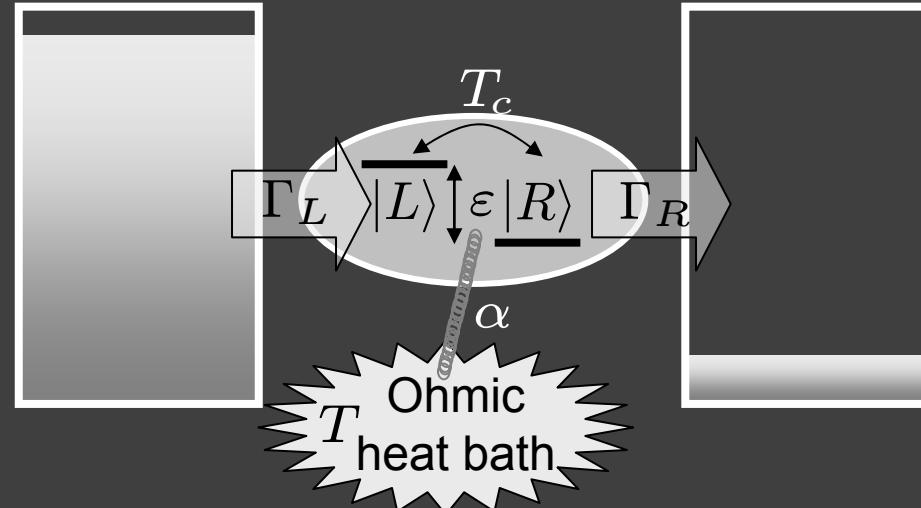
Harvard 2005



ETH-Zürich 2007

Open spin-boson model

Large U , Large bias



$$\hat{H} = \varepsilon \hat{s}_z + T_c \hat{s}_x + \hat{H}_T + \hat{H}_{\text{leads}} + \hat{s}_z \hat{V}_B + \hat{H}_B$$

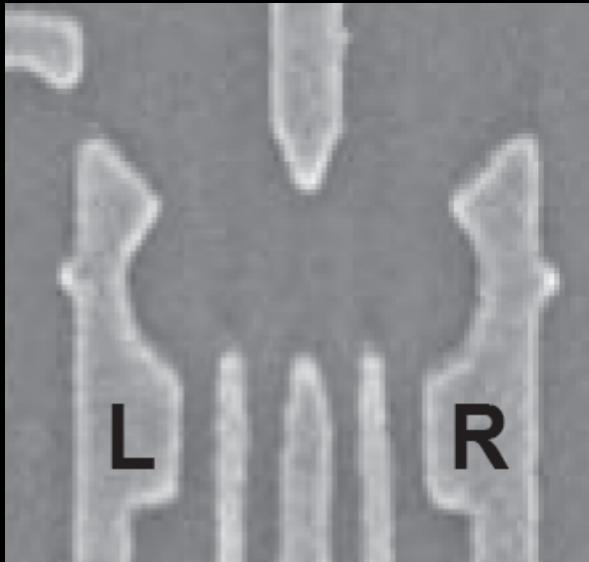
$$\hat{s}_z = |L\rangle\langle L| - |R\rangle\langle R|$$

$$\hat{s}_x = |L\rangle\langle R| + |R\rangle\langle L|$$

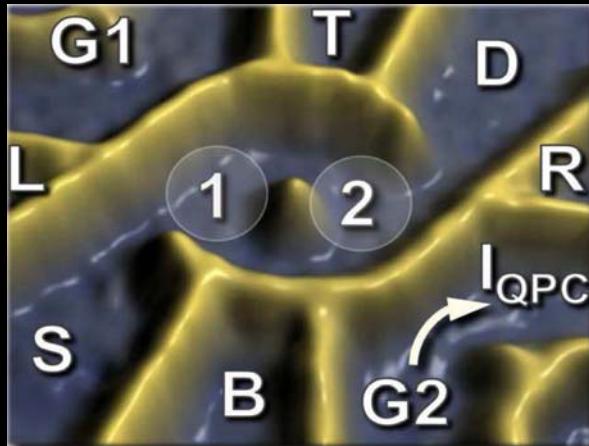
T. Brandes *et al.*, PRL **83**, 3021 (1999)

R. Aguado *et al.*, PRL **92**, 206601 (2004)

Example: dissipative double quantum dot



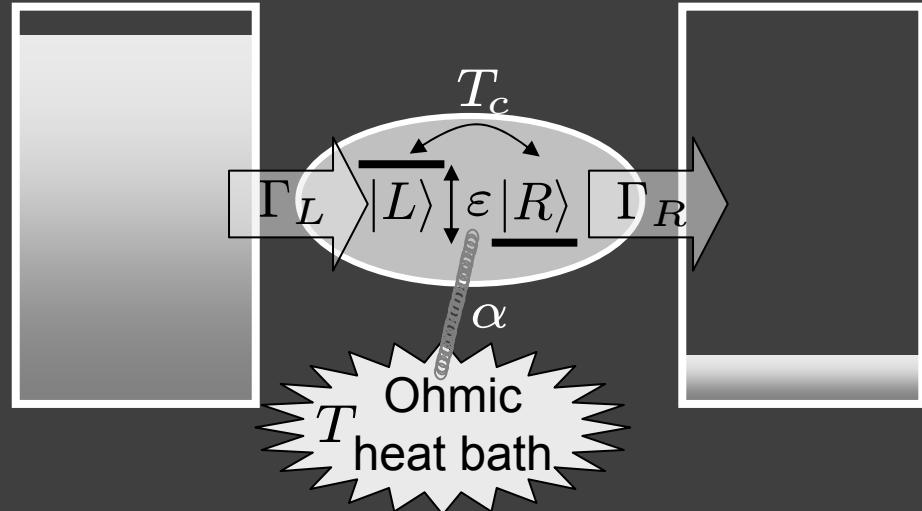
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ETH-Zürich 2007

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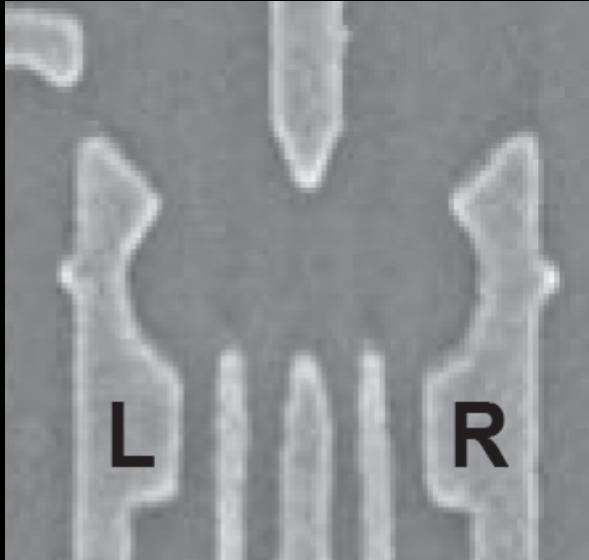
Quantum dot occupations: $\hat{\rho} = (\rho_0, \rho_L, \rho_R)^T$

$$\mathcal{W}(\chi, z) = \begin{pmatrix} -\Gamma_L & 0 & \Gamma_R e^{i\chi} \\ \Gamma_L & -\Gamma_B^{(+)}(z) & \Gamma_B^{(-)}(z) \\ 0 & \Gamma_B^{(+)}(z) & -\Gamma_B^{(-)}(z) - \Gamma_R \end{pmatrix}$$

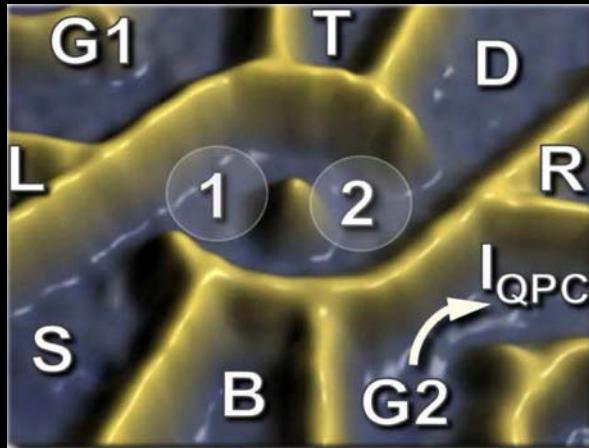
Bath-assisted hopping rates

C. Flindt *et al.*, PRL 100, 150601 (2008) + in prep. (2009)

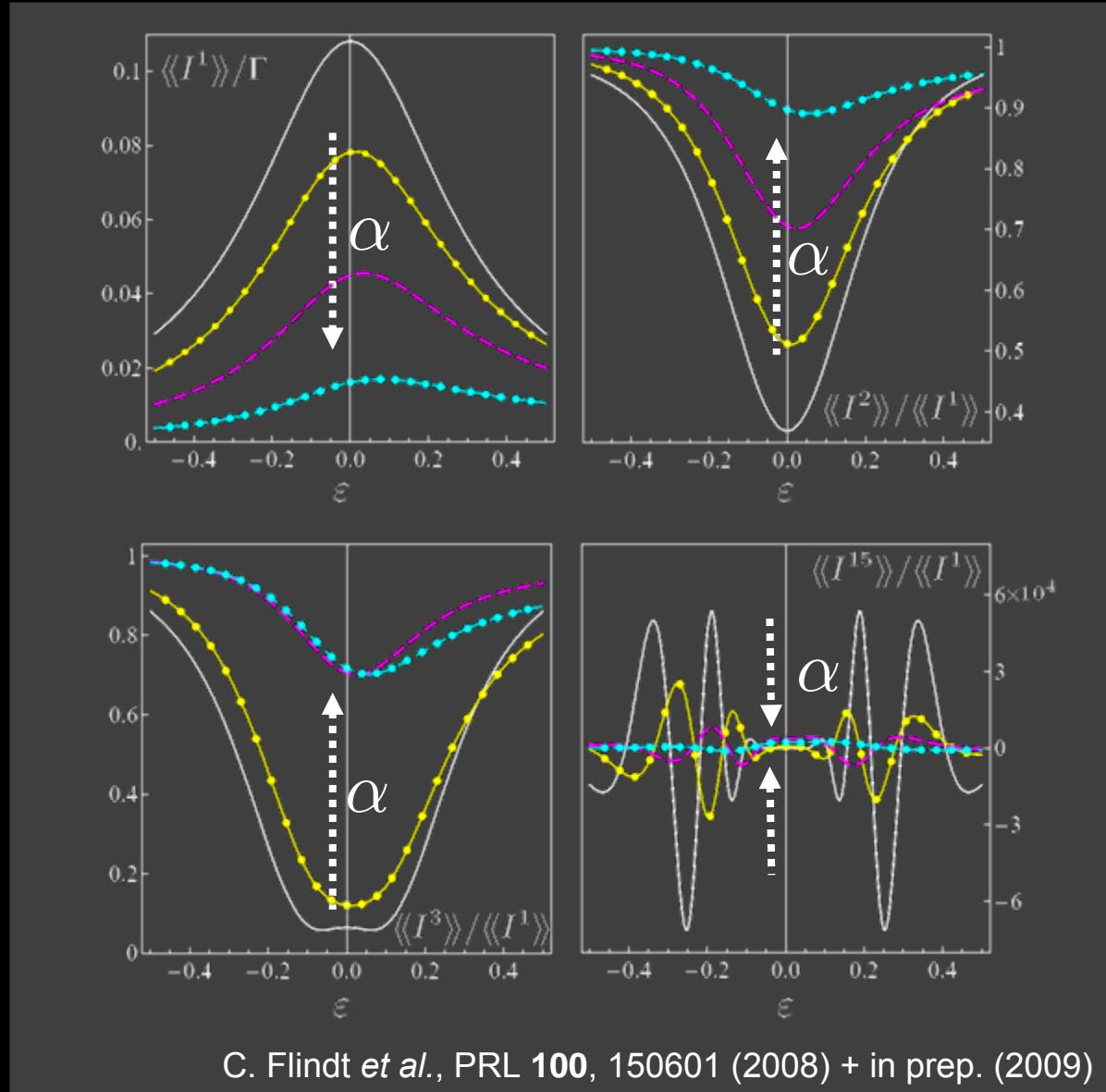
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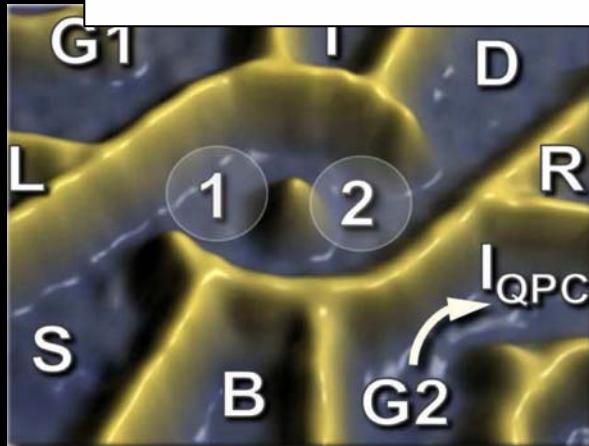
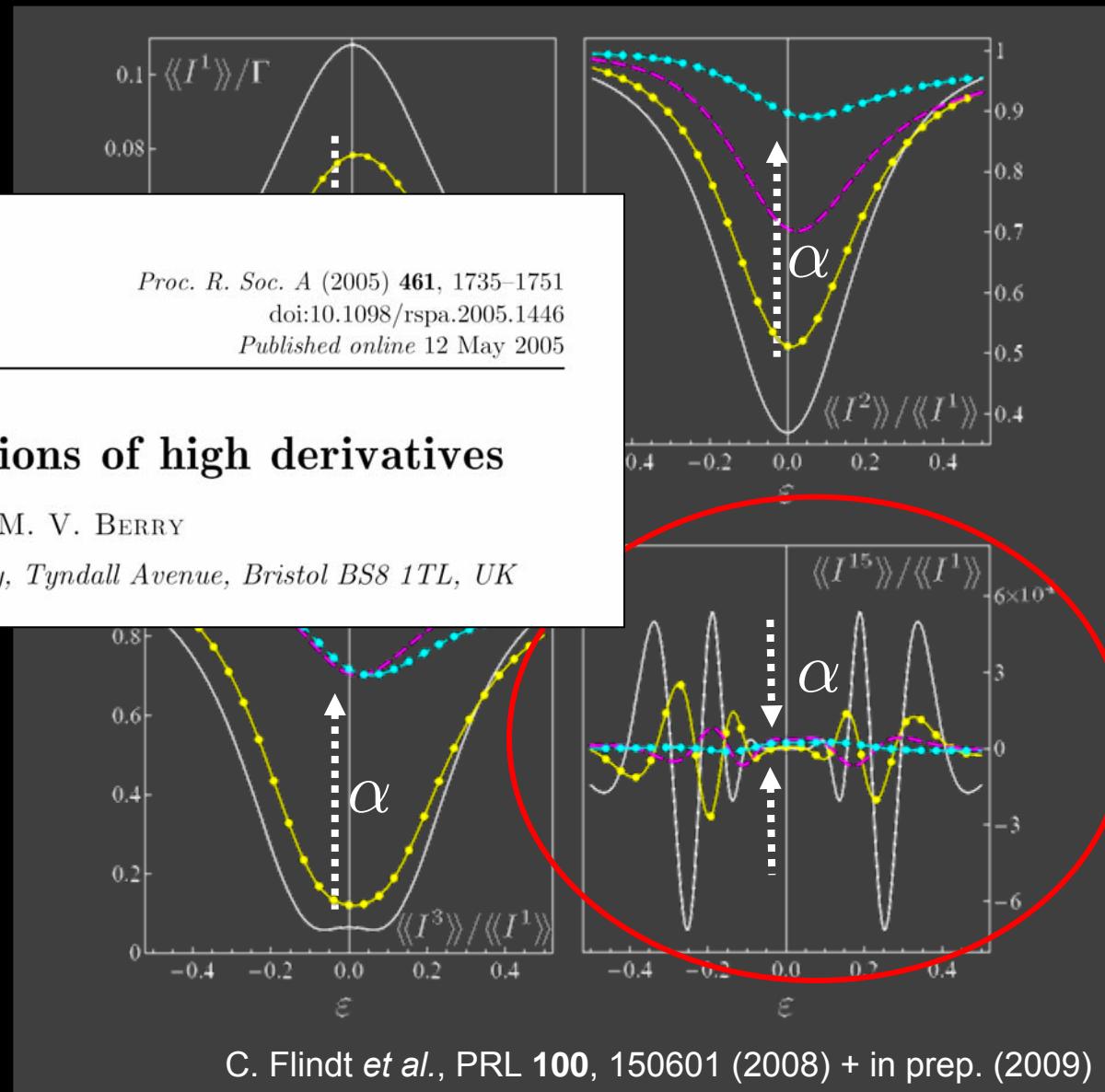
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ETH-Zürich 2007



Example: dissipative double quantum dot

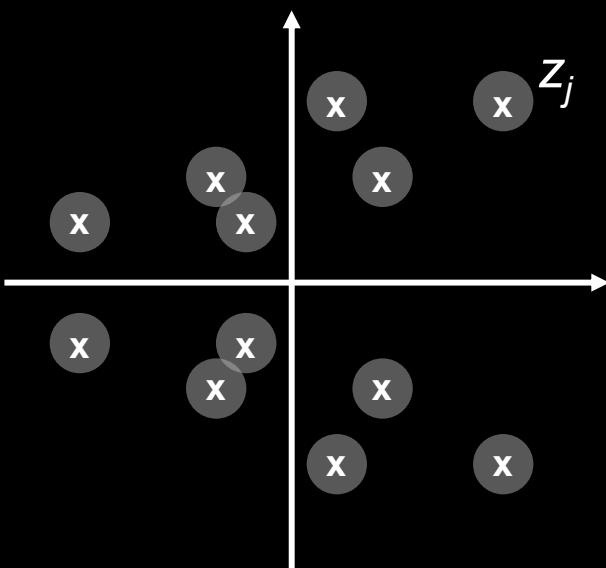


ETH-Zürich 2007

C. Flindt *et al.*, PRL **100**, 150601 (2008) + in prep. (2009)

High-order cumulants

- Cumulants are *derivatives* of the cumulant generating function (CGF)
- High-order derivatives of a function are determined by its singularities in the complex plane [M. V. Berry, Proc. R. Soc. A **461**, 1735 (2005)]
- Consider a general CGF $S(z, \lambda)$ with singularities at $z = z_j$, $j=1,2,3,\dots$
Here λ denotes all relevant system parameters, including time
(entire functions are excluded – e.g. the Poisson process)



Close to a singularity z_j we can write

$$S(z, \lambda) \simeq A_j / (z - z_j)^{\mu_j}$$

for some A_j and μ_j . We then have

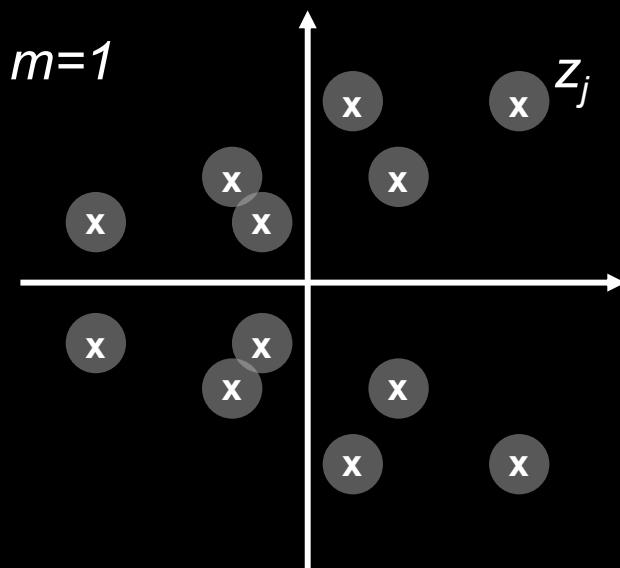
$$\partial_z^m S(z, \lambda) \simeq (-1)^m A_j B_{m, \mu_j} / (z - z_j)^{m + \mu_j}$$

with

$$B_{m, \mu_j} \equiv (m + \mu_j - 1)(m + \mu_j - 2) \dots \mu_j$$

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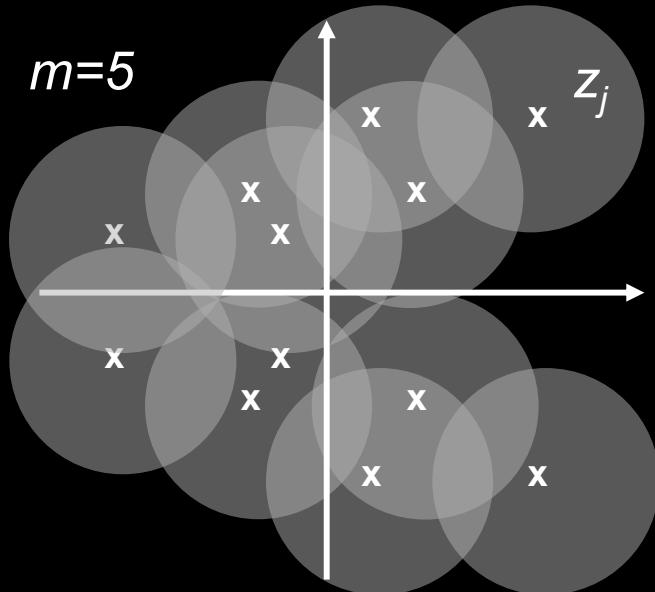
The approximation

$$\partial_z^m S(z, \lambda) \simeq (-1)^m A_j B_{m, \mu_j} / (z - z_j)^{m + \mu_j}$$

becomes increasingly better away from z_j as m is increased (Darboux Theorem).

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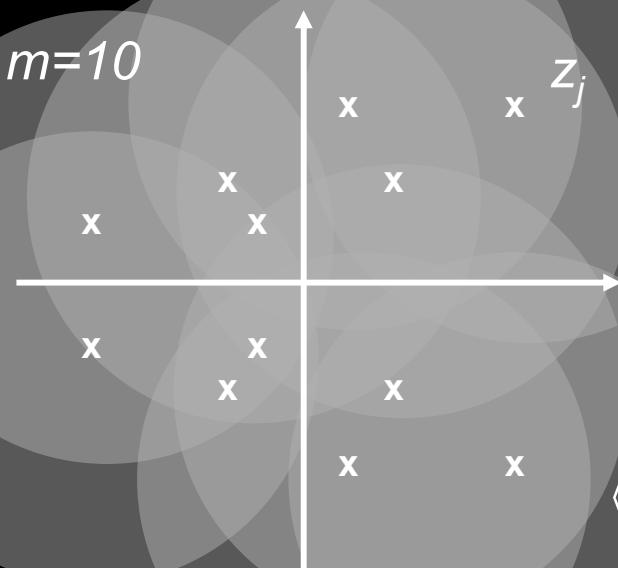
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We thus find

$$\langle\langle n^m \rangle\rangle = \partial_z^m S(z, \lambda) \Big|_{z \rightarrow 0} \rightarrow \sum_j \frac{(-1)^{\mu_j} A_j B_{m, \mu_j}}{z_j^{m + \mu_j}}$$

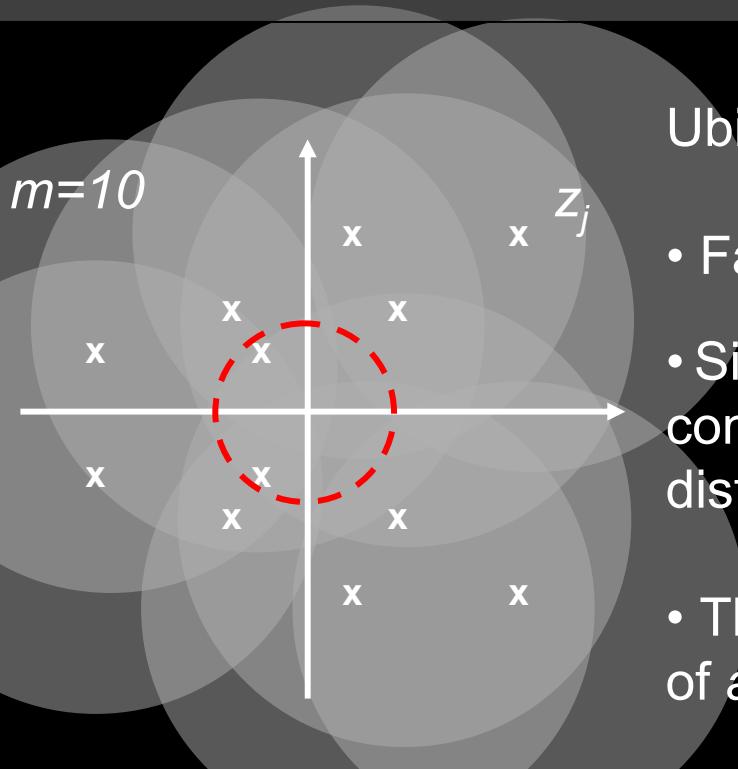
High-order cumulants

The general result

$$\langle\langle n^m \rangle\rangle \simeq \sum_j \frac{(-1)^{\mu_j} A_j B_{m,\mu_j}}{z_j^{m+\mu_j}} = \sum_j \frac{(-1)^{\mu_j} A_j B_{m,\mu_j}}{|z_j|^{m+\mu_j}} e^{-i(m+\mu_j)\phi_j}$$

shows several ubiquitous features. Here $z_j = |z_j| \exp(i\varphi_j)$.

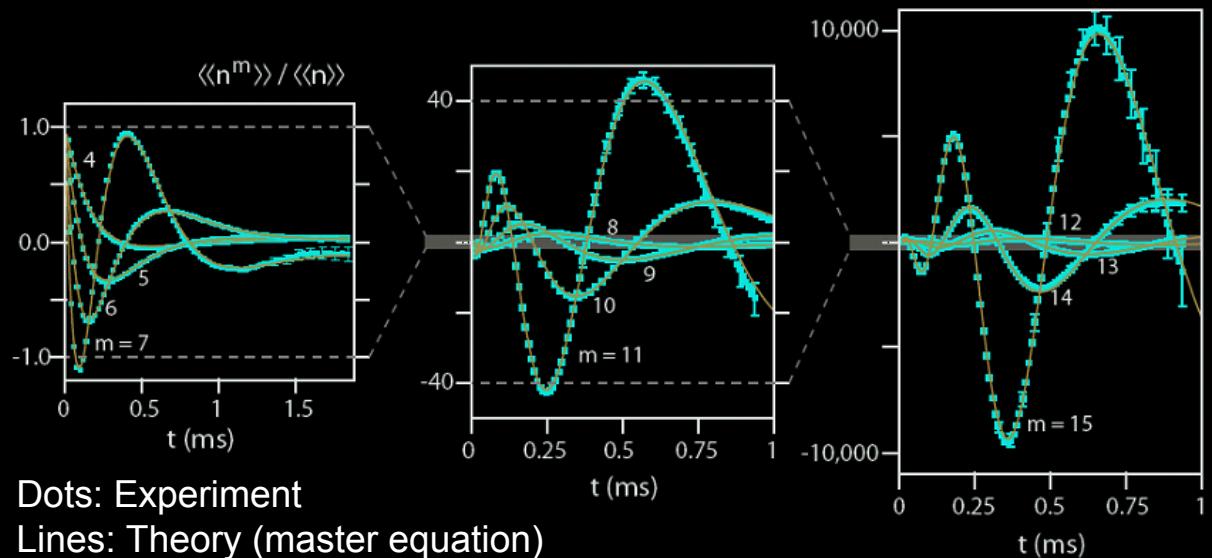
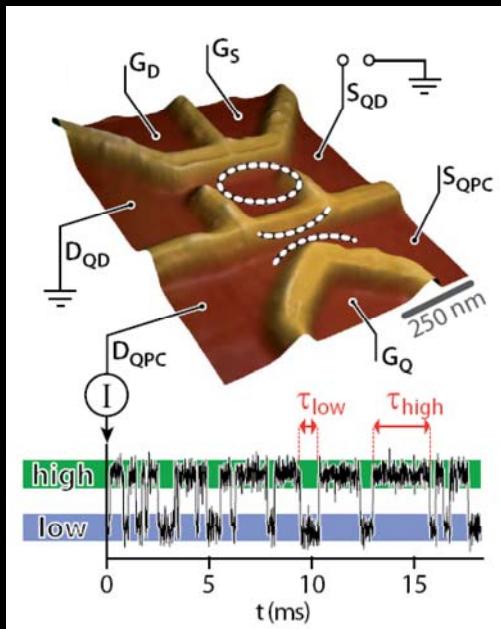
C. Flindt et al., PNAS 106, 10116 (2009)



Ubiquitous features:

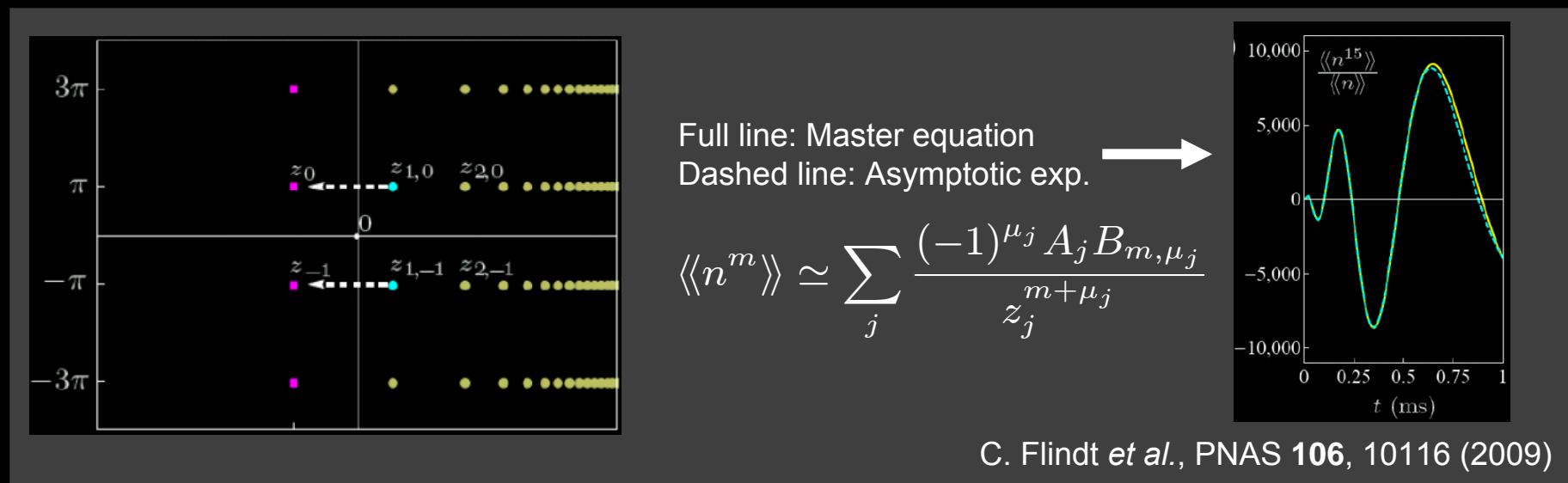
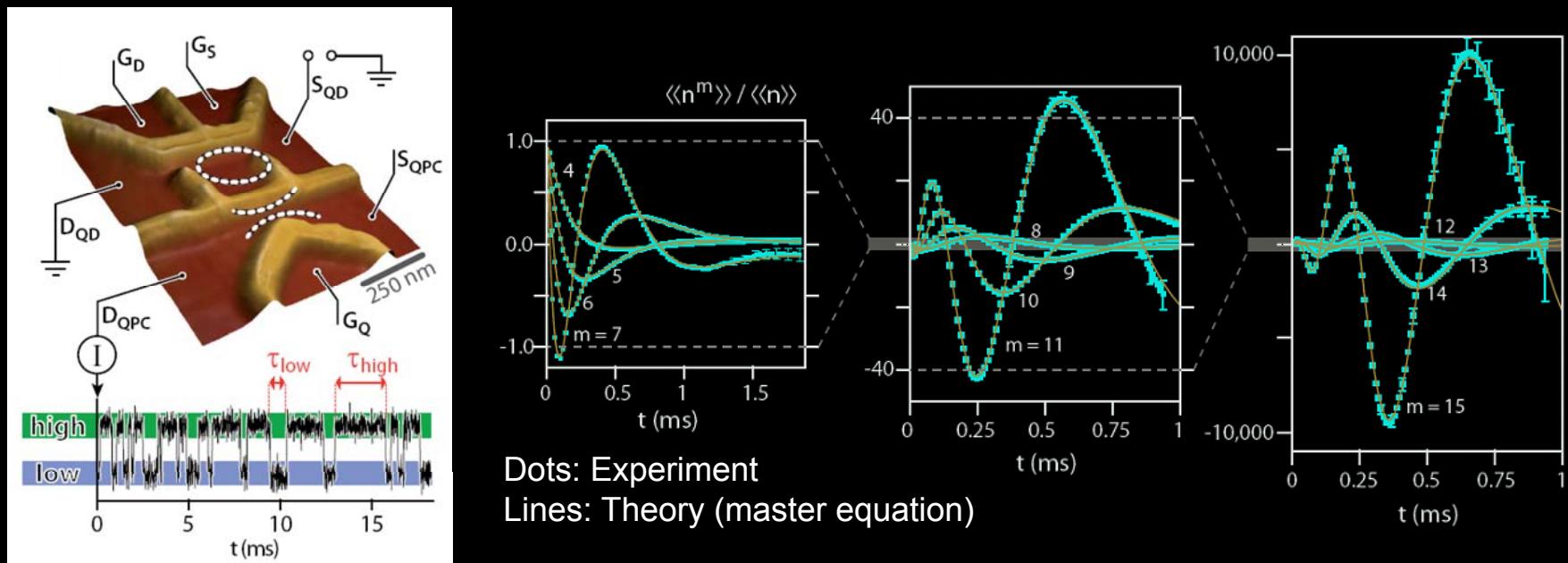
- Factorial growth of cumulants due to B_{m,μ_j}
- Singularities closest to 0 dominate. Other contributions are suppressed with relative distance to 0 and order m
- The cumulants become oscillatory functions of any parameter among λ that changes φ_j

Example: single quantum dot (experiment)



- Single electron counting using nearby quantum point contact [experiment by Hannover group (C. Fricke, F. Hohls, R. J. Haug)]
- Similar experiments at ETH-Zürich (2006) and NTT-Tokyo (2006)
- Cumulants oscillate with time (before reaching linear-in-time regime) and grow factorially in magnitude with the cumulant order

Example: single quantum dot (experiment)



High-order cumulants: Possible applications

PRL 100, 086602 (2008)

PHYSICAL REVIEW LETTERS

week ending
29 FEBRUARY 2008

Allowed Charge Transfers between Coherent Conductors Driven by a Time-Dependent Scatterer

A. G. Abanov^{1,2} and D. A. Ivanov²

¹*Department of Physics and Astronomy, Stony Brook University, Stony Brook, New York 11794-3800, USA*

²*Institute of Theoretical Physics, Ecole Polytechnique Fédérale de Lausanne, CH-1015 Lausanne, Switzerland*

(Received 26 September 2007; published 28 February 2008)

We derive constraints on the statistics of the charge transfer between two conductors in the model of arbitrary time-dependent instant scattering of noninteracting fermions at zero temperature. The constraints are formulated in terms of analytic properties of the generating function—its zeros must lie on the negative real axis. This result generalizes existing studies for scattering by a time-independent scatterer under time-dependent bias voltage.

analytic properties of the generating function

- Abanov & Ivanov have determined the locations of singularities for *non-interacting* electrons [PRL 100, 086602 (2008)]
- Oscillations of high-order cumulants reveal locations of dominating singularities and may be useful to characterize the effects of interactions (work in progress...)

High-order cumulants: Possible applications

PRL 102, 100502 (2009)

PHYSICAL REVIEW LETTERS

week ending
13 MARCH 2009

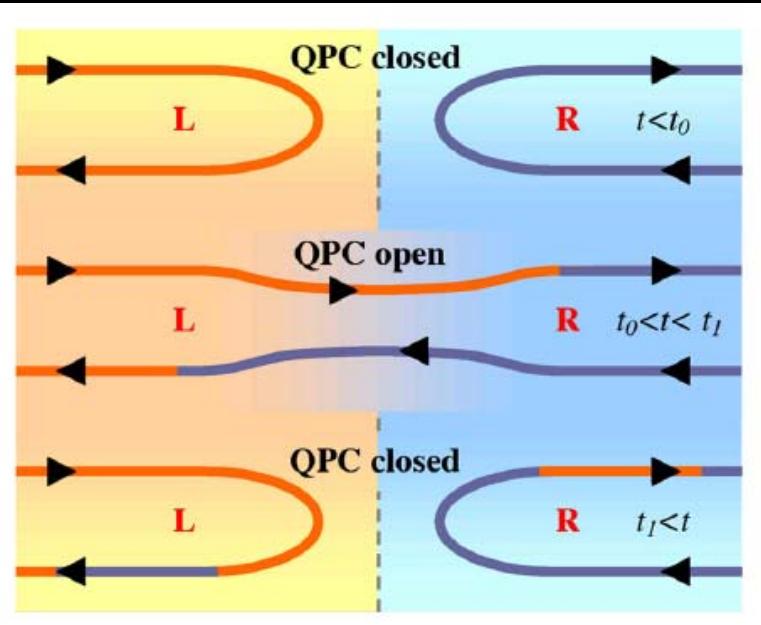
Quantum Noise as an Entanglement Meter

Israel Klich¹ and Leonid Levitov^{1,2}

¹*Kavli Institute for Theoretical Physics, University of California Santa Barbara, Santa Barbara, California 93106, USA*

²*Department of Physics, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA*

(Received 10 June 2008; published 9 March 2009)



Entanglement entropy generated by opening and closing a quantum point contact (QPC) can be related to cumulants:

Only even cumulants are shown to contribute to entropy:

$$S = \sum_{m \geq 0} \frac{\alpha_m}{m!} C_m, \quad \alpha_m = \begin{cases} (2\pi)^m |B_m|, & m \text{ even} \\ 0, & m \text{ odd} \end{cases}, \quad (2)$$

where B_m are Bernoulli numbers [27] ($B_2 = \frac{1}{6}$, $B_4 = -\frac{1}{30}$, $B_6 = \frac{1}{42} \dots$). The first few contributions are

$$S = \frac{\pi^2}{3} C_2 + \frac{\pi^4}{15} C_4 + \frac{2\pi^6}{945} C_6 + \dots \quad (3)$$

What does the behavior of high-order cumulants imply for the entanglement entropy?

Summary

- Introduction to counting statistics
- General theory (open-quantum-systems approach)
Example: a nano-electromechanical system (NEMS)
- Memory effects (due to environment)
Example: dissipative double quantum dot (open spin-boson model)
- High-order cumulants
Example: single quantum dot (experiment)

[Papers: C. Flindt *et al.*, PRL **100**, 150601 (2008), PNAS **106**, 101116 (2009), in prep. (2009)]

Outlook

- High-order cumulants, interacting vs. non-interacting systems, entanglement entropy
- Finite-frequency fluctuations, noise, skewness, ...
(measurements and calculations in progress)

Thank you for your attention!

